

1/4

Fig. 1

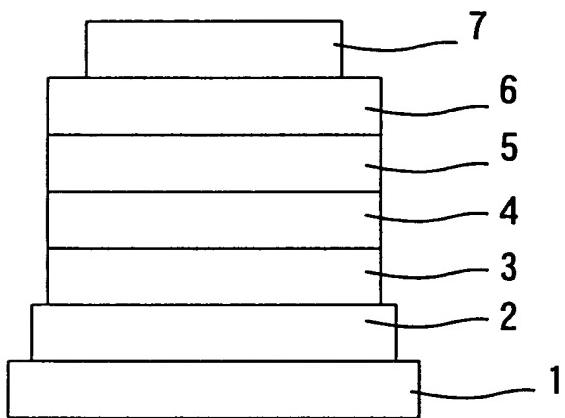
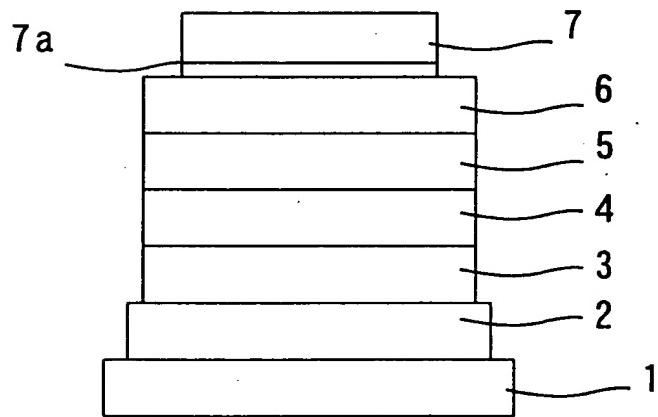


Fig. 2



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2/4

Fig. 3

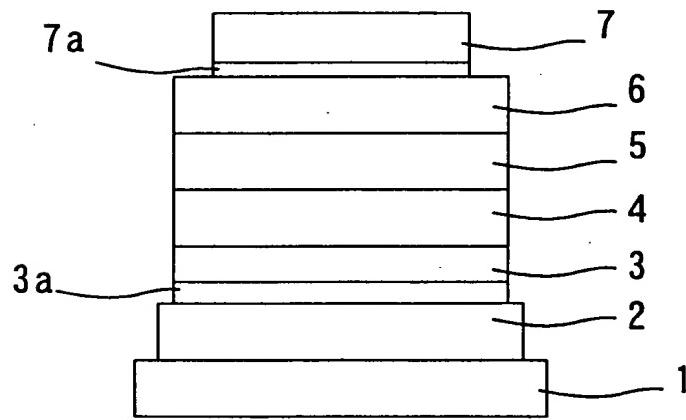
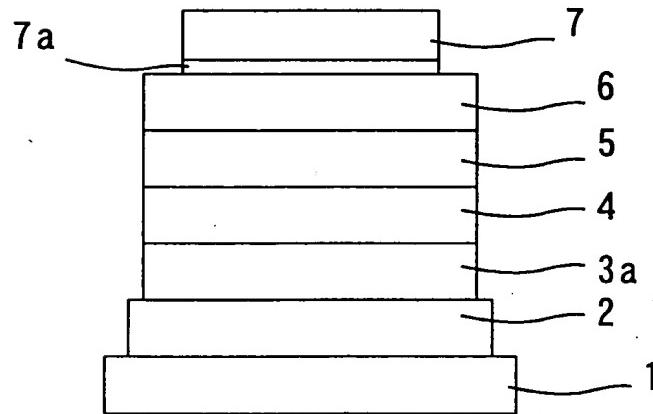
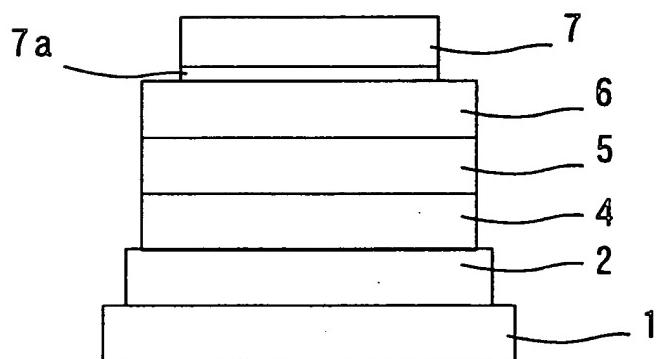


Fig. 4



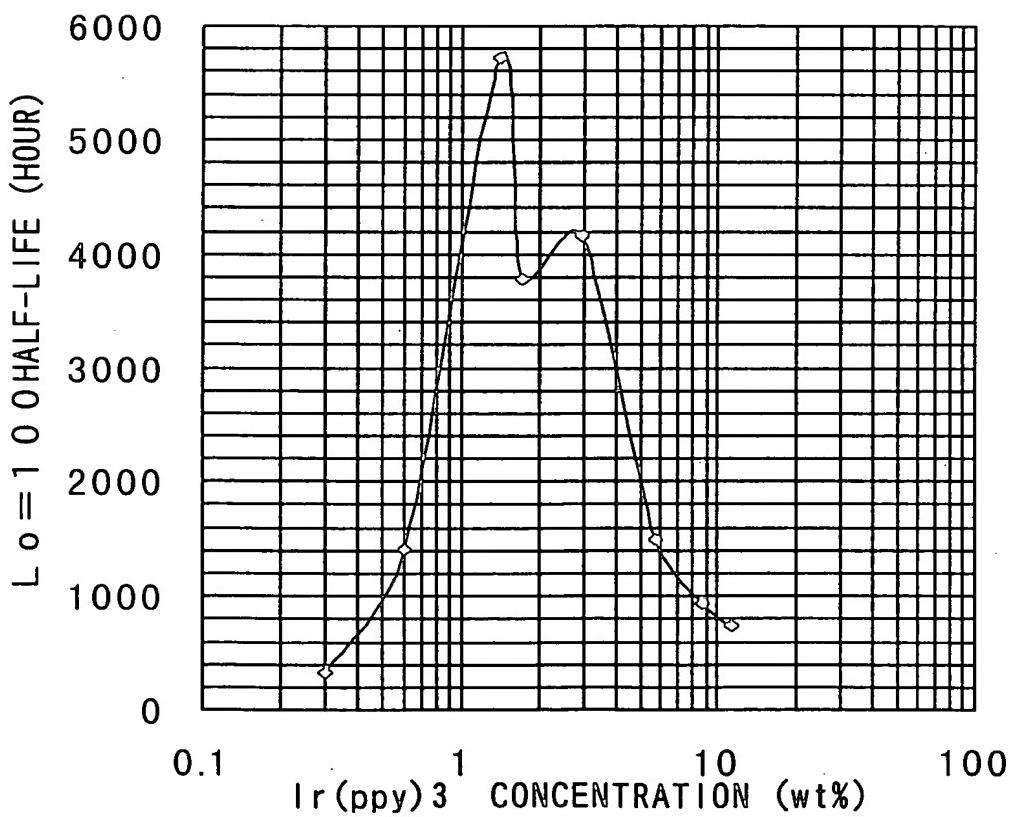
3/4

Fig. 5



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Fig. 7



4/4

Fig. 6

ITO(110nm)NPB(25nm)/CBP(40nm)+Ir(ppy)₃/BCP(10nm)/Alq(40nm)/Li₂O/Al

○	: 11.4 w t %	$L_0 = 1167 \text{ cd/m}^2$
△	: 8.6 w t %	$L_0 = 1338 \text{ cd/m}^2$
□	: 5.7 w t %	$L_0 = 1361 \text{ cd/m}^2$
◇	: 2.9 w t %	$L_0 = 1015 \text{ cd/m}^2$
—	: 1.7 w t %	$L_0 = 737.1 \text{ cd/m}^2$
+	: 1.4 w t %	$L_0 = 770.7 \text{ cd/m}^2$
×	: 0.6 w t %	$L_0 = 606.3 \text{ cd/m}^2$
▽	: 0.3 w t %	$L_0 = 550.2 \text{ cd/m}^2$

